

CMST3904 NPN  
CMST3906 PNP

SURFACE MOUNT  
COMPLEMENTARY  
SILICON TRANSISTORS

**SUPERmini™**



SOT-323 CASE



www.centrasemi.com

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMST3904, CMST3906 types are complementary silicon transistors manufactured by the epitaxial planar process, epoxy molded in a SUPERmini™ surface mount package, designed for small signal general purpose amplifier and switching applications.

**MARKING CODES: CMST3904: 1AC  
CMST3906: 2AC**

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Collector-Base Voltage  
Collector-Emitter Voltage  
Emitter-Base Voltage  
Continuous Collector Current  
Power Dissipation  
Operating and Storage Junction Temperature  
Thermal Resistance

SYMBOL	CMST3904	CMST3906	UNITS
$V_{CBO}$	60	40	V
$V_{CEO}$	40	40	V
$V_{EBO}$	6.0	5.0	V
$I_C$		200	mA
$P_D$		275	mW
$T_J, T_{stg}$		-65 to +150	$^\circ\text{C}$
$\theta_{JA}$		455	$^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	CMST3904		CMST3906		UNITS
		MIN	MAX	MIN	MAX	
$I_{CEV}$	$V_{CE}=30\text{V}, V_{EB}=3.0\text{V}$	-	50	-	50	nA
$BV_{CBO}$	$I_C=10\mu\text{A}$	60	-	40	-	V
$BV_{CEO}$	$I_C=1.0\text{mA}$	40	-	40	-	V
$BV_{EBO}$	$I_E=10\mu\text{A}$	6.0	-	5.0	-	V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$	-	0.20	-	0.25	V
$V_{CE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$	-	0.30	-	0.40	V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$	0.65	0.85	0.65	0.85	V
$V_{BE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$	-	0.95	-	0.95	V
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=0.1\text{mA}$	40	-	60	-	
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=1.0\text{mA}$	70	-	80	-	
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=10\text{mA}$	100	300	100	300	
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=50\text{mA}$	60	-	60	-	
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=100\text{mA}$	30	-	30	-	
$f_T$	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	300	-	250	-	MHz

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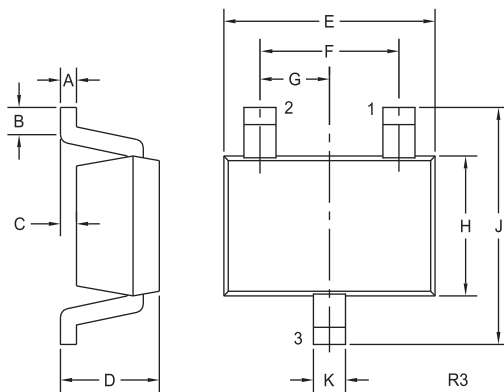
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**ELECTRICAL CHARACTERISTICS - Continued:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	CMST3904		CMST3906		UNITS
		MIN	MAX	MIN	MAX	
$C_{ob}$	$V_{CB}=5.0\text{V}$ , $I_E=0$ , $f=1.0\text{MHz}$	-	4.0	-	4.5	pF
$C_{ib}$	$V_{BE}=0.5\text{V}$ , $I_C=0$ , $f=1.0\text{MHz}$	-	8.0	-	10	pF
$h_{ie}$	$V_{CE}=10\text{V}$ , $I_C=1.0\text{mA}$ , $f=1.0\text{kHz}$	1.0	10	2.0	12	$k\Omega$
$h_{re}$	$V_{CE}=10\text{V}$ , $I_C=1.0\text{mA}$ , $f=1.0\text{kHz}$	0.5	8.0	0.1	10	$\times 10^{-4}$
$h_{fe}$	$V_{CE}=10\text{V}$ , $I_C=1.0\text{mA}$ , $f=1.0\text{kHz}$	100	400	100	400	
$h_{oe}$	$V_{CE}=10\text{V}$ , $I_C=1.0\text{mA}$ , $f=1.0\text{kHz}$	1.0	40	3.0	60	$\mu\text{S}$
NF	$V_{CE}=5.0\text{V}$ , $I_C=100\text{mA}$ , $R_S=1.0k\Omega$ $f=10\text{Hz}$ to $15.7\text{kHz}$	-	5.0	-	4.0	dB
$t_d$	$V_{CC}=3.0\text{V}$ , $V_{BE}=0.5\text{V}$ , $I_C=10\text{mA}$ , $I_{B1}=1.0\text{mA}$	-	35	-	35	ns
$t_r$	$V_{CC}=3.0\text{V}$ , $V_{BE}=0.5\text{V}$ , $I_C=10\text{mA}$ , $I_{B1}=1.0\text{mA}$	-	35	-	35	ns
$t_s$	$V_{CC}=3.0\text{V}$ , $I_C=10\text{mA}$ , $I_{B1}=I_{B2}=1.0\text{mA}$	-	200	-	225	ns
$t_f$	$V_{CC}=3.0\text{V}$ , $I_C=10\text{mA}$ , $I_{B1}=I_{B2}=1.0\text{mA}$	-	50	-	75	ns

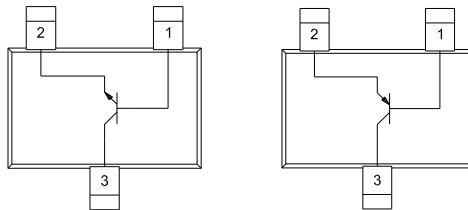
**SOT-323 CASE - MECHANICAL OUTLINE**



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.002	0.008	0.05	0.20
B	0.004	-	0.10	-
C	-	0.004	-	0.10
D	0.031	0.043	0.80	1.10
E	0.071	0.087	1.80	2.20
F	0.051		1.30	
G	0.026		0.65	
H	0.045	0.053	1.15	1.35
J	0.079	0.087	2.00	2.20
K	0.008	0.016	0.20	0.40

SOT-323 (REV: R3)

**PIN CONFIGURATIONS**



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**LEAD CODES:**

- 1) Base
- 2) Emitter
- 3) Collector

**MARKING CODES:**

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